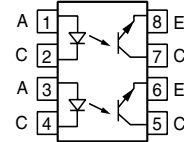
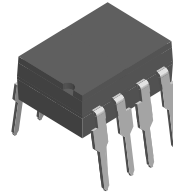


## Optocoupler, Phototransistor Output, Dual Channel

### Features

- Dual Version of SFH610 Series
- Isolation Test Voltage, 5300 V<sub>RMS</sub>
- V<sub>CEsat</sub> 0.25 ( ≤ 0.4 ) V at I<sub>F</sub> = 10 mA, I<sub>C</sub> = 2.5 mA
- V<sub>CEO</sub> = 70 V
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



1179045

### Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- DIN EN 60747-5-2 (VDE0884)  
DIN EN 60747-5-5 pending  
Available with Option 1
- CSA 93751
- BSI IEC60950 IEC60065

### Description

The ILD610 series is a dual channel optocoupler series for high density applications. Each channel consists of an optically coupled pair with a Gallium Arsenide infrared LED and silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and out-

put. The ILD610 series is the dual version of SFH610 series and uses a repetitive pin-out configuration instead of the more common alternating pin-out used in most dual couplers.

### Order Information

| Part         | Remarks                                   |
|--------------|-------------------------------------------|
| ILD610-1     | CTR 40 - 80 %, DIP-8                      |
| ILD610-2     | CTR 63 - 125 %, DIP-8                     |
| ILD610-3     | CTR 100 - 200 %, DIP-8                    |
| ILD610-4     | CTR 160 - 320 %, DIP-8                    |
| ILD610-2X007 | CTR 63 - 125 %, SMD-8 (option 7)          |
| ILD610-3X006 | CTR 100 - 200 %, DIP-8 400 mil (option 6) |
| ILD610-3X009 | CTR 100 - 200 %, SMD-8 (option 9)         |
| ILD610-4X009 | CTR 160 - 320 %, SMD-8 (option 9)         |

For additional information on the available options refer to Option Information.

### Absolute Maximum Ratings

T<sub>amb</sub> = 25 °C, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

### Input

| Parameter                  | Test condition | Symbol            | Value | Unit  |
|----------------------------|----------------|-------------------|-------|-------|
| Reverse voltage            |                | V <sub>R</sub>    | 6.0   | V     |
| Surge forward current      | t ≤ 10 ms      | I <sub>FSM</sub>  | 1.5   | A     |
| Power dissipation          |                | P <sub>diss</sub> | 100   | mW    |
| Derate linearly from 25 °C |                |                   | 1.3   | mW/°C |
| DC forward current         |                | I <sub>F</sub>    | 60    | mA    |

## Output

| Parameter                  | Test condition  | Symbol     | Value | Unit  |
|----------------------------|-----------------|------------|-------|-------|
| Collector-emitter voltage  |                 | $V_{CE}$   | 70    | V     |
| Collector current          |                 | $I_C$      | 50    | mA    |
|                            | $t \leq 1.0$ ms | $I_C$      | 100   | mA    |
| Power dissipation          |                 | $P_{diss}$ | 150   | mW    |
| Derate linearly from 25 °C |                 |            | 2.0   | mW/°C |

## Coupler

| Parameter                     | Test condition                       | Symbol    | Value          | Unit      |
|-------------------------------|--------------------------------------|-----------|----------------|-----------|
| Isolation test voltage        | $t = 1.0$ sec.                       | $V_{ISO}$ | 5300           | $V_{RMS}$ |
| Isolation resistance          | $V_{IO} = 500$ V, $T_{amb} = 25$ °C  | $R_{IO}$  | $\geq 10^{12}$ | $\Omega$  |
|                               | $V_{IO} = 500$ V, $T_{amb} = 100$ °C | $R_{IO}$  | $\geq 10^{11}$ | $\Omega$  |
| Storage temperature           |                                      | $T_{stg}$ | - 55 to + 150  | °C        |
| Operating temperature         |                                      | $T_{amb}$ | - 55 to + 100  | °C        |
| Junction temperature          |                                      | $T_j$     | 100            | °C        |
| Lead soldering time at 260 °C |                                      |           | 10             | sec.      |

## Electrical Characteristics

$T_{amb} = 25$  °C, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

## Input

| Parameter       | Test condition             | Symbol | Min | Typ. | Max  | Unit    |
|-----------------|----------------------------|--------|-----|------|------|---------|
| Forward voltage | $I_F = 60$ mA              | $V_F$  |     | 1.25 | 1.65 | V       |
| Reverse current | $V_R = 6.0$ V              | $I_R$  |     | 0.01 | 10   | $\mu$ A |
| Capacitance     | $V_R = 0$ V, $f = 1.0$ MHz | $C_O$  |     | 25   |      | pF      |

## Output

| Parameter                           | Test condition                    | Part     | Symbol     | Min | Typ. | Max | Unit |
|-------------------------------------|-----------------------------------|----------|------------|-----|------|-----|------|
| Collector-emitter breakdown voltage | $I_C = 10$ mA, $I_E = 10$ $\mu$ A |          | $BV_{CEO}$ | 70  | 90   |     | V    |
|                                     |                                   |          | $BV_{CEO}$ | 6.0 | 7.0  |     | V    |
| Collector-emitter dark current      | $V_{CE} = 10$ V                   |          | $I_{CEO}$  |     | 2.0  | 50  | nA   |
| Collector-emitter capacitance       | $V_{CE} = 5.0$ V, $f = 1.0$ MHz   |          | $C_{CE}$   |     | 7.0  |     | pF   |
| Collector-emitter leakage current   | $V_{CE} = 10$ V                   | ILD610-1 | $I_{CEO}$  |     | 2.0  | 50  | nA   |
|                                     |                                   | ILD610-2 | $I_{CEO}$  |     | 2.0  | 50  | nA   |
|                                     |                                   | ILD610-3 | $I_{CEO}$  |     | 5.0  | 100 | nA   |
|                                     |                                   | ILD610-4 | $I_{CEO}$  |     | 5.0  | 100 | nA   |

## Coupler

| Parameter                            | Test condition                | Symbol      | Min | Typ. | Max  | Unit |
|--------------------------------------|-------------------------------|-------------|-----|------|------|------|
| Collector-emitter saturation voltage | $I_F = 10$ mA, $I_C = 2.5$ mA | $V_{CEsat}$ |     | 0.25 | 0.40 | V    |
| Coupling capacitance                 |                               | $C_C$       |     | 0.35 |      | pF   |

## Current Transfer Ratio

| Parameter         | Test condition                                    | Part     | Symbol | Min | Typ. | Max | Unit |
|-------------------|---------------------------------------------------|----------|--------|-----|------|-----|------|
| CTR <sup>1)</sup> | $I_F = 10 \text{ mA}$ , $V_{CE} = 5.0 \text{ V}$  | ILD610-1 | CTR    | 40  |      | 80  | %    |
|                   |                                                   | ILD610-2 | CTR    | 63  |      | 125 | %    |
|                   |                                                   | ILD610-3 | CTR    | 100 |      | 200 | %    |
|                   |                                                   | ILD610-4 | CTR    | 160 |      | 320 | %    |
|                   | $I_F = 1.0 \text{ mA}$ , $V_{CE} = 5.0 \text{ V}$ | ILD610-1 | CTR    | 13  |      |     | %    |
|                   |                                                   | ILD610-2 | CTR    | 22  |      |     | %    |
|                   |                                                   | ILD610-3 | CTR    | 34  |      |     | %    |
|                   |                                                   | ILD610-4 | CTR    | 56  |      |     | %    |

<sup>1)</sup>CTR will match within a ratio of 1.7:1

## Switching Characteristics

Non-saturated

| Parameter     | Test condition                                             | Part     | Symbol    | Min | Typ. | Max | Unit  |
|---------------|------------------------------------------------------------|----------|-----------|-----|------|-----|-------|
| Rise time     | $V_{CC} = 5.0$ , $R_L = 75 \Omega$ , $I_F = 10 \text{ mA}$ | ILD610-1 | $t_r$     |     | 2.0  |     | $\mu$ |
|               |                                                            | ILD610-2 | $t_r$     |     | 2.5  |     | $\mu$ |
|               |                                                            | ILD610-3 | $t_r$     |     | 2.9  |     | $\mu$ |
|               |                                                            | ILD610-4 | $t_r$     |     | 3.3  |     | $\mu$ |
| Fall time     | $V_{CC} = 5.0$ , $R_L = 75 \Omega$ , $I_F = 10 \text{ mA}$ | ILD610-1 | $t_f$     |     | 2.0  |     | $\mu$ |
|               |                                                            | ILD610-2 | $t_f$     |     | 2.6  |     | $\mu$ |
|               |                                                            | ILD610-3 | $t_f$     |     | 3.1  |     | $\mu$ |
|               |                                                            | ILD610-4 | $t_f$     |     | 3.5  |     | $\mu$ |
| Turn-on time  | $V_{CC} = 5.0$ , $R_L = 75 \Omega$ , $I_F = 10 \text{ mA}$ | ILD610-1 | $t_{on}$  |     | 3.0  |     | $\mu$ |
|               |                                                            | ILD610-2 | $t_{on}$  |     | 3.2  |     | $\mu$ |
|               |                                                            | ILD610-3 | $t_{on}$  |     | 3.6  |     | $\mu$ |
|               |                                                            | ILD610-4 | $t_{on}$  |     | 2.3  |     | $\mu$ |
| Turn-off time | $V_{CC} = 5.0$ , $R_L = 75 \Omega$ , $I_F = 10 \text{ mA}$ | ILD610-1 | $t_{off}$ |     | 2.9  |     | $\mu$ |
|               |                                                            | ILD610-2 | $t_{off}$ |     | 3.4  |     | $\mu$ |
|               |                                                            | ILD610-3 | $t_{off}$ |     | 3.7  |     | $\mu$ |
|               |                                                            | ILD610-4 | $t_{off}$ |     | 4.1  |     | $\mu$ |

Saturated

| Parameter    | Test condition                                                        | Part     | Symbol   | Min | Typ. | Max | Unit  |
|--------------|-----------------------------------------------------------------------|----------|----------|-----|------|-----|-------|
| Rise time    | $V_{CC} = 5.0$ , $R_L = 1.0 \text{ k}\Omega$ , $I_F = 5.0 \text{ mA}$ | ILD610-1 | $t_r$    |     | 2.0  |     | $\mu$ |
|              |                                                                       | ILD610-2 | $t_r$    |     | 2.8  |     | $\mu$ |
|              |                                                                       | ILD610-3 | $t_r$    |     | 3.3  |     | $\mu$ |
|              |                                                                       | ILD610-4 | $t_r$    |     | 4.6  |     | $\mu$ |
| Fall time    | $V_{CC} = 5.0$ , $R_L = 1.0 \text{ k}\Omega$ , $I_F = 5.0 \text{ mA}$ | ILD610-1 | $t_f$    |     | 11   |     | $\mu$ |
|              |                                                                       | ILD610-2 | $t_f$    |     | 2.6  |     | $\mu$ |
|              |                                                                       | ILD610-3 | $t_f$    |     | 3.1  |     | $\mu$ |
|              |                                                                       | ILD610-4 | $t_f$    |     | 15   |     | $\mu$ |
| Turn-on time | $V_{CC} = 5.0$ , $R_L = 1.0 \text{ k}\Omega$ , $I_F = 5.0 \text{ mA}$ | ILD610-1 | $t_{on}$ |     | 3.0  |     | $\mu$ |
|              |                                                                       | ILD610-2 | $t_{on}$ |     | 4.3  |     | $\mu$ |
|              |                                                                       | ILD610-3 | $t_{on}$ |     | 4.6  |     | $\mu$ |
|              |                                                                       | ILD610-4 | $t_{on}$ |     | 6.0  |     | $\mu$ |

| Parameter     | Test condition                                                      | Part     | Symbol    | Min | Typ. | Max | Unit  |
|---------------|---------------------------------------------------------------------|----------|-----------|-----|------|-----|-------|
| Turn-off time | $V_{CC} = 5.0$ , $R_L = 1.0\text{ k}\Omega$ , $I_F = 5.0\text{ mA}$ | ILD610-1 | $t_{off}$ |     | 18   |     | $\mu$ |
|               |                                                                     | ILD610-2 | $t_{off}$ |     | 2.9  |     | $\mu$ |
|               |                                                                     | ILD610-3 | $t_{off}$ |     | 3.4  |     | $\mu$ |
|               |                                                                     | ILD610-4 | $t_{off}$ |     | 25   |     | $\mu$ |

## Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

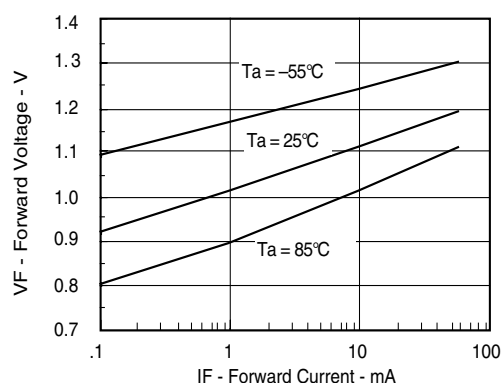


Figure 1. Forward Voltage vs. Forward Current

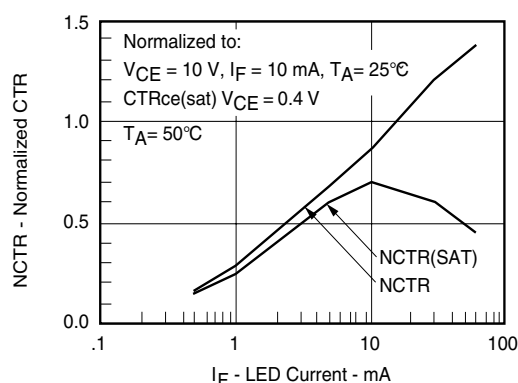


Figure 3. Normalized Non-Saturated and Saturated CTR vs. LED Current

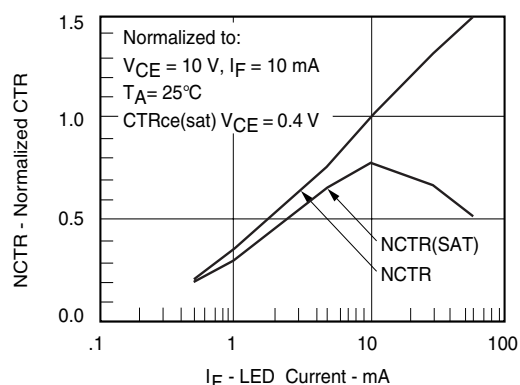


Figure 2. Normalized Non-Saturated and Saturated CTR vs. LED Current

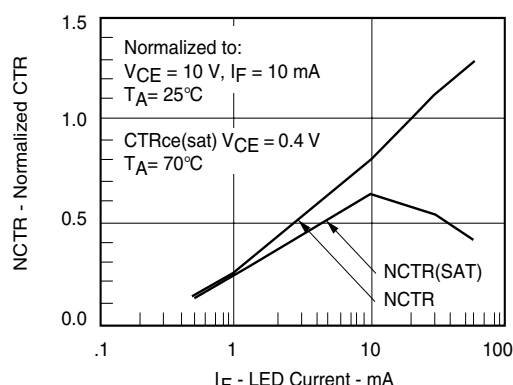
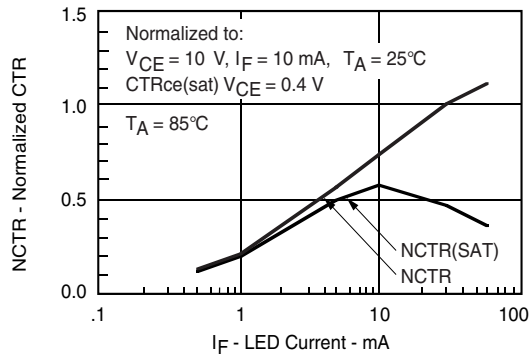
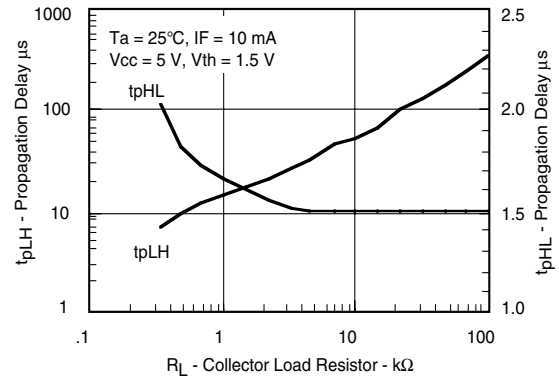


Figure 4. Normalized Non-Saturated and Saturated CTR vs. LED Current



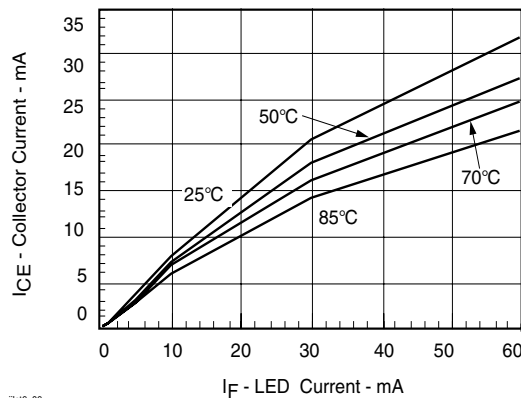
ilc6\_05

Figure 5. Normalized Non-Saturated and Saturated CTR vs. LED Current



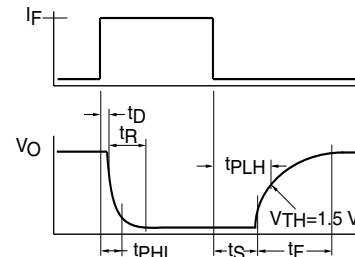
ilc6\_08

Figure 8. Propagation Delay vs. Collector Load Resistor



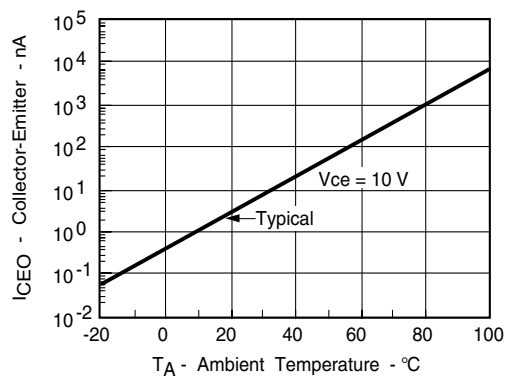
ilc6\_06

Figure 6. Collector-Emitter Current vs. Temperature and LED Current



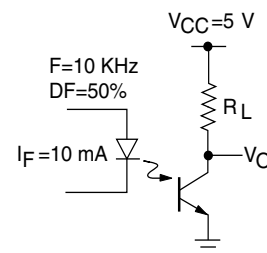
ilc610\_09

Figure 9. Switching Timing



ilc6\_07

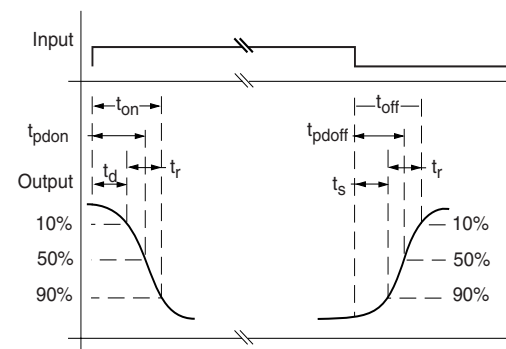
Figure 7. Collector-Emitter Leakage Current vs. Temp.



ilc610\_10

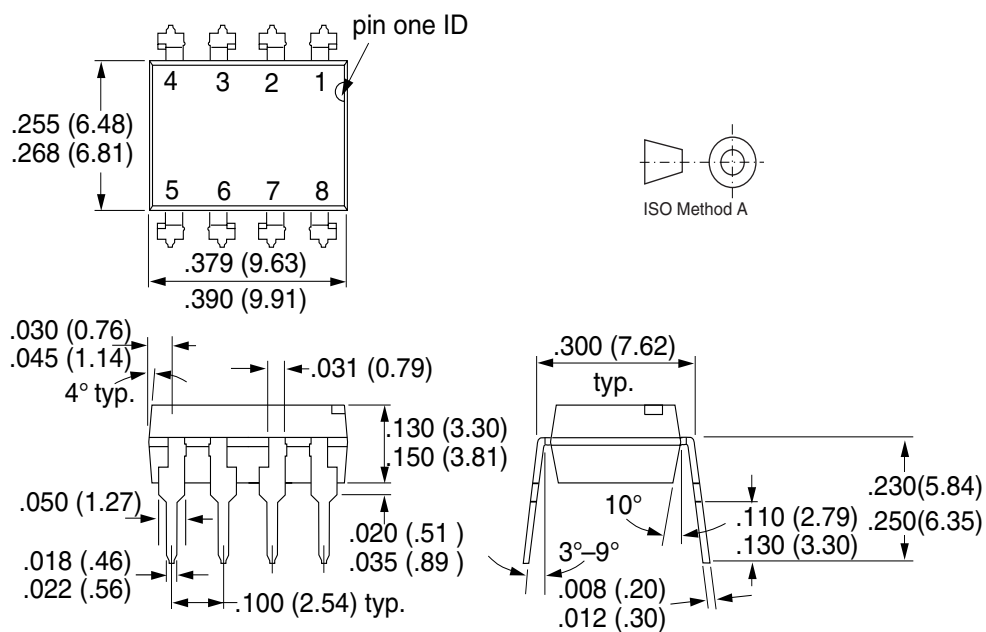
Figure 10. Non-saturated Switching Schematic

Figure 11. Saturated Switching Time Test Waveform



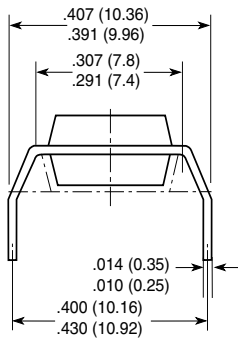
ild610\_11

## Package Dimensions in Inches (mm)

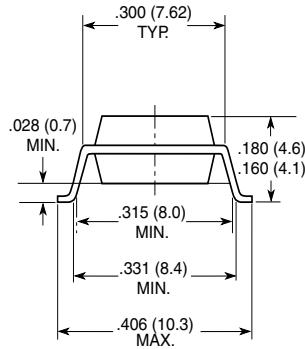


i178006

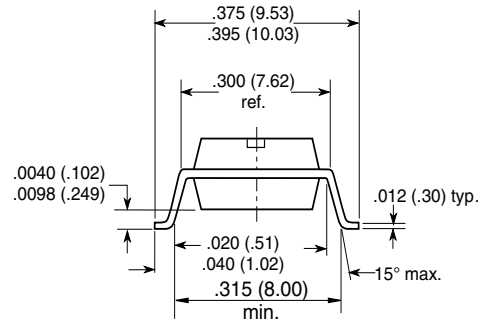
**Option 6**



**Option 7**



**Option 9**



18450

### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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